

DESCRIPTION

The PT2476 is 1 Full-On Drive H-Bridge channel with three different packages. The driver features wide range operating from 2V to 24V and low power consumption by fast switching speed.

FEATURES

- It is low consumption by BCD process adoption
- One small package: HSOP8
- Wide power-supply voltage range:
 Control (VCC): 2.7V to 5.5V
 Motor (VM): 2.0V~24V
- High DC output current: Max.=2.8A
- Ultra low RDSON(TOP+BOT): 0.49ΩTYP@25°C, 1A
- Low current consumption when power-down: <0.05µA @25°C
- PWM control, Max. input frequency: 200KHz
- Operating temperature range: -40 to +85°C
- Charge-pump less
- Shoot-through current protection
- Built-in protection circuits
 - Under Voltage Lock Out
 - Thermal Shut Down
- OCP

BLOCK DIAGRAM



APPLICATION

- Lens for DSLR
- Auto icemaker or dumper drive for refrigerator
- HV bi-direction DC Motor
- Intelligent electronic lock



APPLICATION CIRCUITS

HSOP8





ORDER INFORMATION

Valid Part Number	Package Type	Top Code
PT2476-HS	8 pins, HSOP	PT2476-HS

PIN CONFIGURATION



PIN DESCRIPTION

Pin Name I/O		Description	Pin No.
Fin Name	1/0	Description	HSOP8
AGND	GND	Logic GND	1
VCC	Power	Power supply for Logic circuit	2
VM	Power	Power supply for driver	3
OUTA	0	H-Bridge output terminal A of the driver	4
OUTB	0	H-Bridge output terminal B of the driver	5
INA	I	Control input	6
INB	I	Control input	7
EN	I	Logic Enable [300KΩ pull up for VCC]	8
PGND	GND	Power MOS GND	Thermal PAD



FUNCTION DESCRIPTION

INPUT/OUTPUT CONFIGURATION

INA, INB





OUTA, OUTB



Note:

INA=INB=H and EN=H, OUTA and OUTB are low level in brake state, here the power NMOS NA and NB are on, the enable NMOS ENA and ENB are off. The NA and NB have the ability of sink current.

INA=INB=X and EN=L, OUTA and OUTB are low level in off state, here the power NMOS NA and NB are off, the enable NMOS ENA and ENB are on. The ENA and ENB only pull down the OUTA and OUTB, and they haven't the ability of sink current.



INPUT-OUTPUT LOGIC TABLE

EN	Input	Input Signal		Driver		
EN	INA	INB	OUTA	OUTB	Actuator status	
Н	L	L	Z	Z	Standby	
Н	L	Н	L	Н	Reverse	
Н	Н	L	Н	L	Forward	
Н	Н	Н	L	L	Brake	
L	Х	Х	L	L	Off	

FUNCTION SEQUENCE



Note: VM & VCC power on have no timing sequence

VM & VCC power off have no timing sequence

EN power on have no timing sequence

EN power off have no timing sequence



THERMAL SHUTDOWN (TSD) CIRCUIT

The PT2476 includes a thermal shutdown circuit, which turns the output transistors off when the junction temperature (Tj) exceeds 175°C (typ.).

The output transistors are automatically turned on when Tj cools past the shutdown threshold, which is lowered by a hysteresis of 30°C.

TSD = 175°C ΔTSD = 30°C

* In thermal shutdown mode, the circuits powered by VCC are work normal, and the circuits powered by VM are shut down.

UNDER VOLTAGE LOCKOUT (UVLO) CIRCUIT

The PT2476 includes an under voltage lockout circuit, which puts the output transistors in the high-impedance state when VCC decreases to 2.13V (typ.) or lower.

The output transistors are automatically turned on when VCC increases past the lockout threshold, which is raised to 2.21 V by a hysteresis of 0.08 V.

* In UVLO shutdown mode, a part of circuits powered by VCC are work normal, and the circuits powered by VM are shut down.

SHOOT-THROUGH CURRENT PROTECTION

During Dead Time (Shoot through current circuit is operated.), Power MOS both of HI side and Low side are turned off. But in this time, internal parasitic diode is turned on according to current direction.

OVER-CURRENT PROTECTION

In the PT2476, a current monitor will protect the IC from damage due to output shorts. The internal Overcurrent Protection (OCP) has the following features:

If a short is detected, then the fault will be latched, and the IC will disable the outputs. The fault latch can only be cleared by reset EN pin or by cycling the power to VM



ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Min	Max	Unit	Note
Supply voltage VCC	VCC	-0.5	6	V	-
Control input voltage	INA/INB/EN	-0.5	6	V	-
Supply voltage VM	VM	-0.5	26	V	-
H-Bridge output current DC	lload_dc_MD	-	2.8	А	-
H-Bridge output current AC	lload_peak_MD	- - -	5.0	A	Note1
Continuous power dissipation	Pd Ta=85℃	-	1083	mW	Note2
Operation temperature	Та	-40	85	°C	-
Junction temperature	Tj	-	150	°C	-
Storage temperature	Tstg	-40	150	°C	-
Minimum ESD rating(HBM)	Vesd	2000	-	V	-
Minimum ESD rating(MM)	Vesd	200	-	V	-

Notes:

1. Terminal OUTA,OUTB pulse with =<200ms :Duty 1%

 Glass epoxy board : 4 layer circuit board, Rj=39°C/W EP pin is connected to GND. (EP pin has 4 thermal VIA holes.)

RECOMMENDED OPERATION CONDITIONS

Parameter	Symbol	Min	Тур.	Мах	Unit
Supply voltage VCC	VCC	2.7	3.3	5.5	V
Control input voltage	INA/INB/EN	1.62	1.8/3.3	VCC	V
Supply voltage VM	VM	2	-	24	V
Logic input frequency	Fin	0	-	200	KHz
Logic input duty for frequency=200KHz (Ta=25℃, VCC=3.3V, VM=12V, Rload=50Ω)	Duty	6%	-	94%	%



ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, Ta=25°C, VCC=3.3V, VM=7.4V)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
VDET				- 71		
VCC UVLO	VCDET_LV		1.90	2.13	2.50	V
TSD (Note)		I				
Thermal shut down temperature	TDET		-	175	-	°C
Hysteresis	TDETHYS		-	30	-	°C
OCP						
Over current protection trip level	IOCP			3.6		А
Over current deglitch time	ldgt			2		uS
Power supply current	Ŭ					
VM standby current1	IVM_NOPOW	VCC=L	-	0.005	0.05	μA
VM standby current2	IVM_STBY	EN=L	-	0.005	0.05	μA
VCC work current	IVCC_WORK	EN=H, INA=INB=L	-	110	300	μA
VCC off current	IVCC_OFF	EN=L	-	11	30	μA
Operation circuit current	IVCC_PWM	INA=200KHz, INB=H	-	0.38	0.8	mA
Driver						
Output on resistance 1	RON1	VCC=3.3V, Iout=100mA	_	0.23	0.27	Ω
(HSD or LSD)		Ta=25°C		0.20	0.27	32
Output on resistance 2 (HSD or LSD)	RON2	VCC=3.3V, lо∪т=1.0A Та=25°С (Тј=65°С)	-	0.245	0.29	Ω
Output on resistance 3 (HSD or LSD)	RON3	VCC=3.3V,I _{0∪T} =1.0A Ta=85°C (Tj=125°C)	-	0.295	0.35	Ω
Diode forward voltage	VF_MD	IF=100mA	-	0.7	1.2	V
Control terminal	_					
H level input voltage (INA, INB, EN)	VIH		0.7xVCC	-	-	V
L level input voltage (INA, INB, EN)	VIL		-	-	0.3xVCC	V
H level input current (INA, INB)	IIH1	EN=H or L	-	-	1	μA
L level input current (INA, INB)	IIL1	EN=H or L	-	-	1	μA
H level input current (EN)	IIH1		-	-	1	μA
L level input current (EN)	IIL1		-	11	30	μA
Full Swing	•					
Turn on time 1	TfONH	VCC=3.3V, VM=7.4V	-	0.42	1.0	μs
Turn off time 1	TfOFFH	Ι _{ουτ} =500mA,	-	0.11	0.5	μs
Output rise time 1	Tfr	Output state: Forward→Reverse.	-	0.09	1.0	μs
Output fall time 1	Tff	Refer to Fig.1	-	0.04	0.5	μs
Turn on time 2	TrONH	VCC=3.3V, VM=7.4V	-	0.38	1.0	μs
Turn off time 2	TrOFFH	Ιουτ =500m Α,	-	0.11	0.5	μs
Output rise time 2	Trr	Output state: Reverse→Forward.	-	0.09	1.0	μs
Output fall time 2	Trf	Refer to Fig.1	-	0.04	0.5	μs

Note: OUTA and OUTB are Hi-Z (off state) at thermal shut down.



SWITCHING CHARACTERISTICS WAVEFORM

SWITCHING WAVEFORM







OCP CHARACTERISTICS WAVEFORM

OUTPUT SHORTED WAVEFORM







PACKAGE INFORMATION

8-PIN, HSOP









Symbol	Dimensions(mm)					
	Min.	Nom.	Max.			
A	-	-	1.70			
A1	0.00	-	0.15			
A2	1.25	-	-			
b	0.31	-	0.51			
С	0.10	-	0.25			
е		1.27 BSC				
D		4.90 BSC				
D1	2.81	-	3.30			
E		6.00 BSC				
E1		3.90 BSC				
E2	2.05	-	2.41			
L	0.40	0.60	1.27			
θ	0°	-	8°			

Notes:

1. Refer to JEDEC MS-012 BA

2. All dimensions are in millimeter.

3. D1 and E2 refer to supplier spec. The JEDEC MS-012BA classify D1 and E2 minimum value are 1.5mm and 1.0mm.



IMPORTANT NOTICE

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